## NSN 5962-01-039-3456

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-039-3456

View Online at https://aerobasegroup.com/nsn/5962-01-039-3456
Body Length:
Between 0.750 inches and 0.795 inches
Body Width:
Between 0.245 inches and 0.300 inches
Body Height:
Between 0.120 inches and 0.195 inches
Maximum Power Dissipation Rating:
512.0 milliwatts
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+160.0 degrees celsius
End Application:
Data display group type ol-17 (v) /uyk
Features Provided:
Hermetically sealed and monolithic and high speed and negative outputs and positive outputs and programmable and programmed and
schottky and w/enable and 3-state output
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Case Outline Source And Designator:
-0-001-ag joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Memory Device Type:
Ram
Test Data Document:
46859-398-14171 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

## NSN 5962-01-039-3456

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0